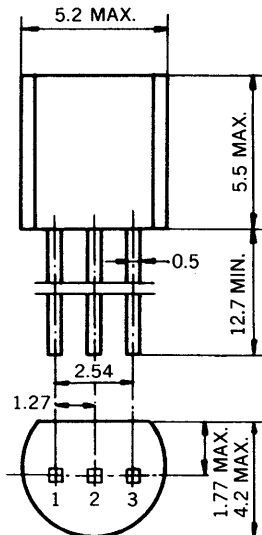
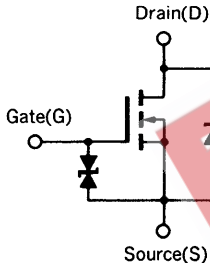


N-CHANNEL MOS FET
FOR SWITCHING

PACKAGE DIMENSIONS (Unit : mm)



- 1. Gate
- 2. Drain
- 3. Source



(Diode in the figure is the parasitic diode.)

The 2SK1484, N-channel vertical type MOS FET, is a switching device which can be driven directly by the output of ICs having a 5 V power source.

As the MOS FET has low on-state resistance and excellent switching characteristics, it is suitable for driving actuators such as motors, relays, and solenoids.

FEATURES

- Directly driven by ICs having a 5 V power source.
- Has low on-state resistance
 $R_{DS(on)1} = 1.2 \Omega \text{ MAX. @ } V_{GS} = 4.0 \text{ V, } I_D = 0.5 \text{ A}$
 $R_{DS(on)2} = 0.8 \Omega \text{ MAX. @ } V_{GS} = 10 \text{ V, } I_D = 0.5 \text{ A}$
- Can be used complementary with the 2SJ198

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

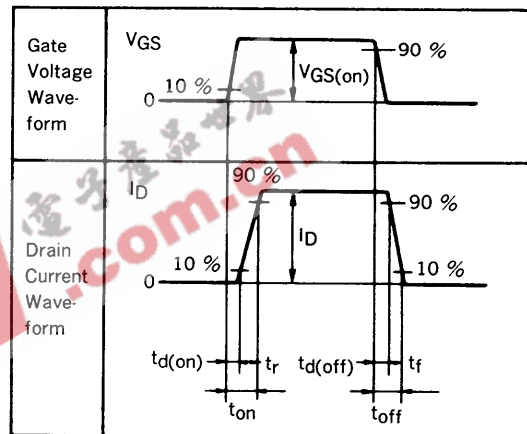
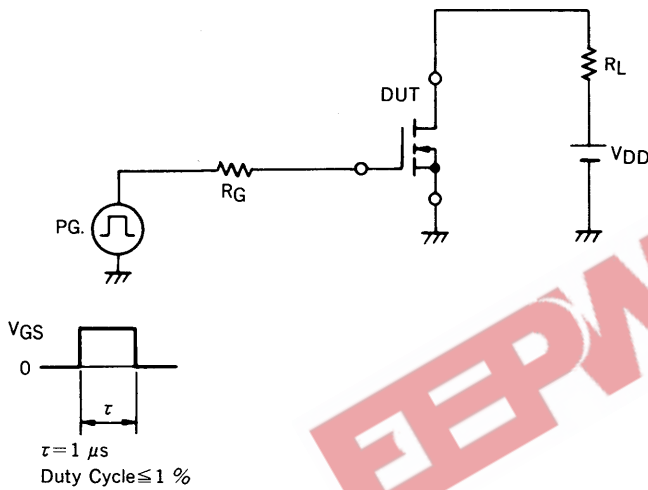
ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS
Drain to Source Voltage	V_{DSS}	100	V	$V_{GS} = 0$
Gate to Source Voltage	V_{GSS}	± 20	V	$V_{DS} = 0$
Drain Current	$I_D(\text{DC})$	± 500	mA	
Drain Current	$I_D(\text{pulse})$	± 1.0	A	$PW \leq 10 \text{ ms, Duty Cycle} \leq 50 \%$
Total Power Dissipation	P_T	750	mW	
Channel Temperature	T_{ch}	150	$^\circ\text{C}$	
Storage Temperature	T_{stg}	$-55 \text{ to } +150$	$^\circ\text{C}$	

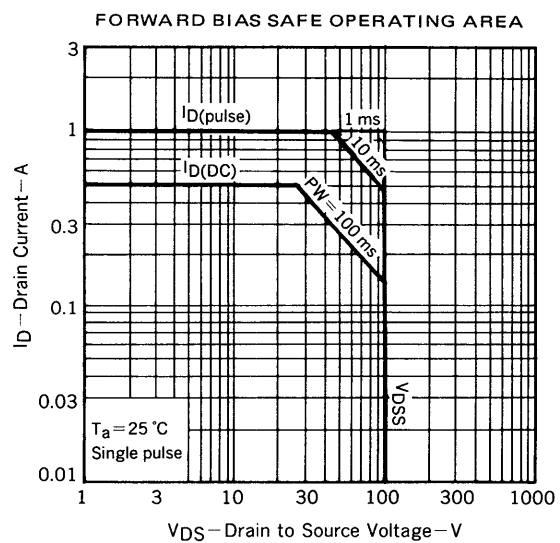
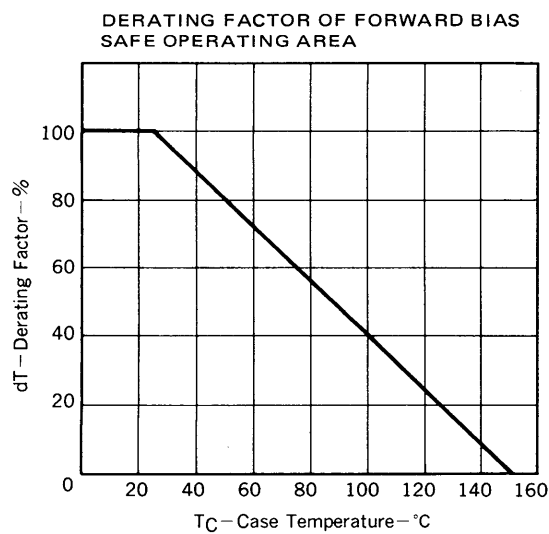
ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain Cut-off Current	I _{DSS}			10	μA	V _{DS} = 100 V, V _{GS} = 0
Gate Leakage Current	I _{GSS}			±10	μA	V _{GS} = ±20 V, V _{DS} = 0
Gate Cut-off Voltage	V _{GS(off)}	0.8	1.2	2.0	V	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance	y _{fs}	0.4			S	V _{DS} = 10 V, I _D = 0.5 A
Drain to Source On-State Resistance	R _{DS(on)1}		0.6	1.2	Ω	V _{GS} = 4.0 V, I _D = 0.5 A
Drain to Source On-State Resistance	R _{DS(on)2}		0.5	0.8	Ω	V _{GS} = 10 V, I _D = 0.5 A
Input Capacitance	C _{iss}		230		pF	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz
Output Capacitance	C _{oss}		80		pF	
Feedback Capacitance	C _{rss}		12		pF	
Turn-On Delay Time	t _{d(on)}		14		ns	V _{GS(on)} = 10 V, R _G = 10 Ω V _{DD} = 25 V, I _D = 0.5 A R _L = 50 Ω
Rise Time	t _r		14		ns	
Turn-Off Delay Time	t _{d(off)}		370		ns	
Fall Time	t _f		65		ns	

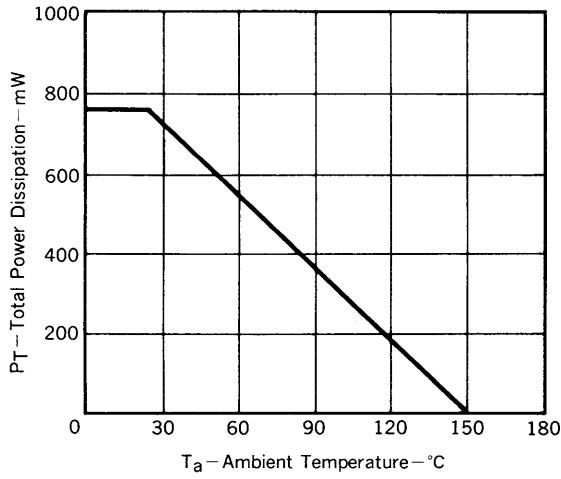
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS



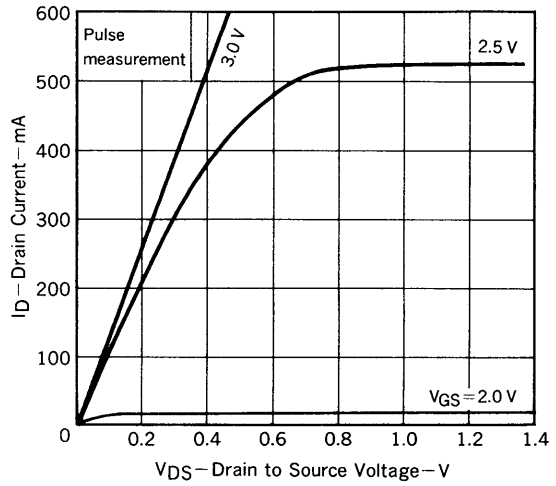
TYPICAL CHARACTERISTICS (T_a = 25 °C)



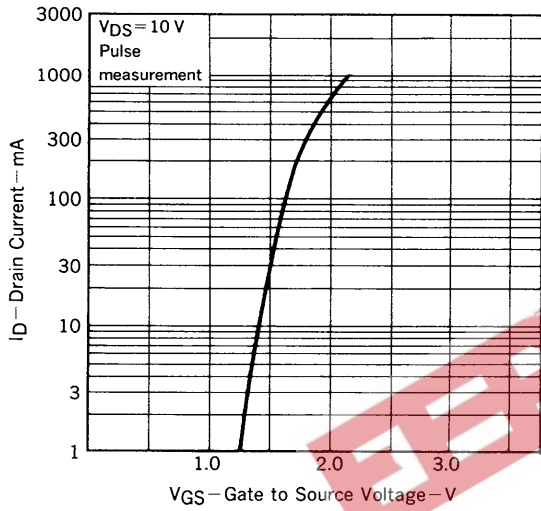
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



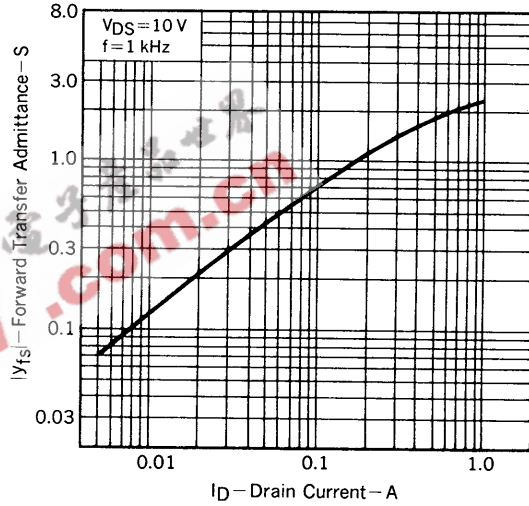
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



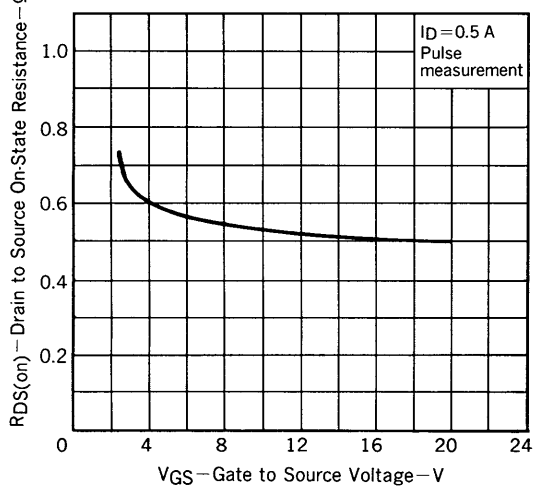
TRANSFER CHARACTERISTICS



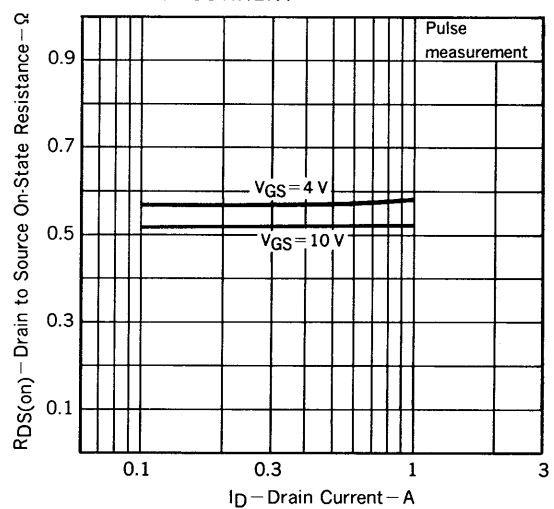
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



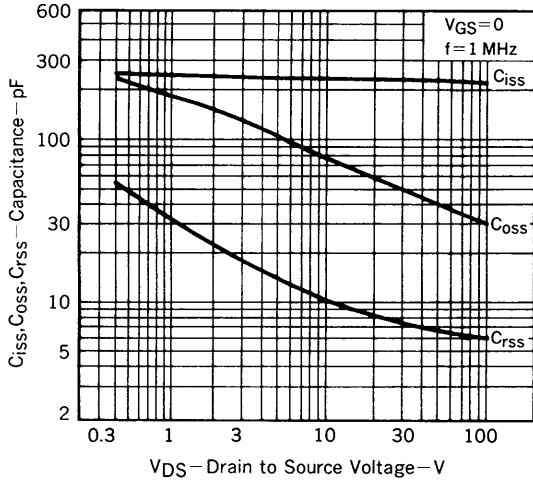
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



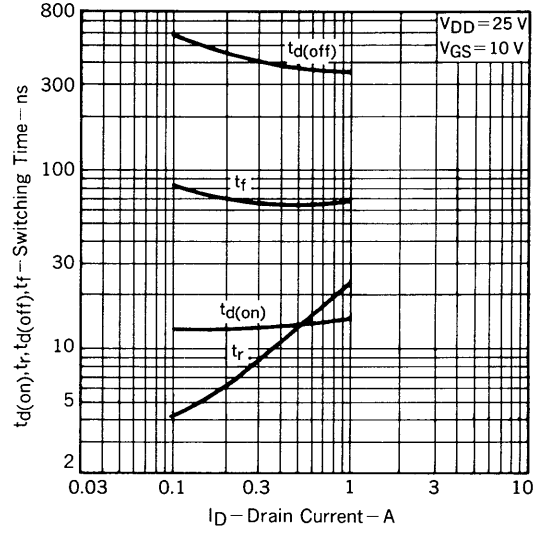
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



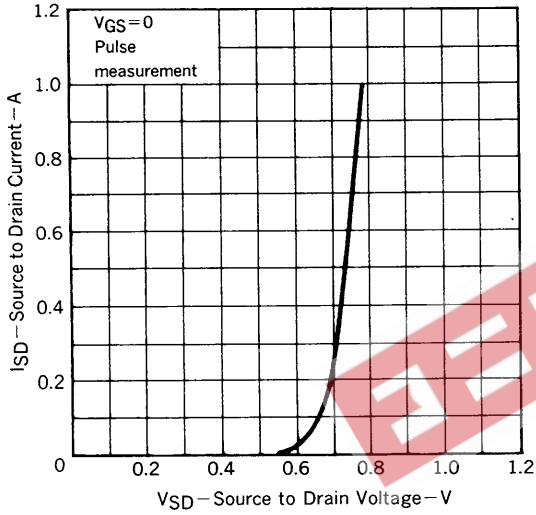
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SWITCHING CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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RECOMMENDED SOLDERING CONDITIONS

Solder this product under the following recommended conditions.

For soldering methods or soldering conditions other than those recommended in the table, please consult our NEC salespeople.

Insert type

Soldering method	Soldering conditions	Recommended condition code
Wave soldering	Solder bath temperature: 260 °C max. Soldering time: 10 sec max.	



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The devices listed in this document are not suitable for use in the field where very high reliability is required including, but not limited to, aerospace equipment, submarine cables, nuclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or those intended to use "Standard", or "Special" quality grade NEC devices for the applications not intended by NEC, please contact our sales people in advance.

Application examples recommended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile), Test and Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line), Train and Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime systems etc.